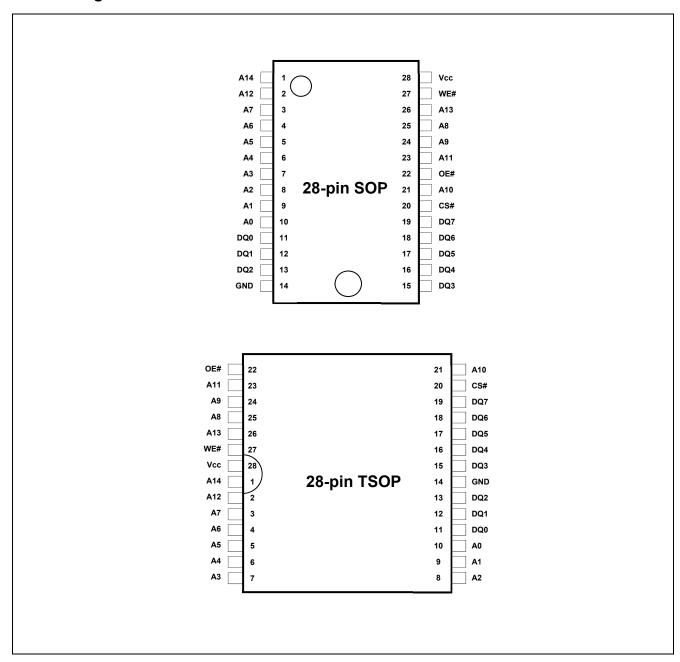
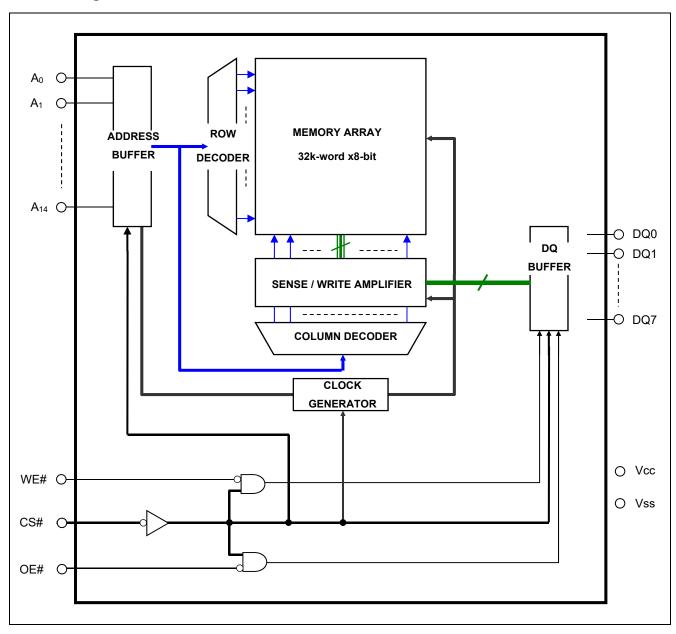
Pin Arrangement



Pin Description

Pin name	Function
Vcc	Power supply
Vss (GND)	Ground
A0 to A14	Address input
DQ0 to DQ7	Data input/output
CS#	Chip select
WE#	Write enable
OE#	Output enable

Block Diagram



Operation Table

CS#	WE#	OE#	DQ0~7	Operation
Н	Х	Х	High-Z	Stand-by
L	L	Х	Din	Write
L	Н	L	Dout	Read
L	Н	Н	High-Z	Output disable

Note 1. H: V_{IH} L: V_{IL} X: V_{IH} or V_{IL}

Absolute Maximum

Parameter	Symbol	Value	unit
Power supply voltage relative to Vss	Vcc	-0.3 to +7.0	V
Terminal voltage on any pin relative to Vss	V _T	-0.3*1 to Vcc+0.3*2	V
Power dissipation	P _T	0.7	W
Operation temperature	Topr	-40 to +85	°C
Storage temperature range	Tstg	-65 to 150	°C
Storage temperature range under bias	Tbias	-40 to +85	°C

Note 1. –3.0V for pulse ≤ 30ns (full width at half maximum)

^{2.} Maximum voltage is +7.0V.

DC Operating Conditions

Parameter	Symbol	Min.	Тур.	Max.	Unit	Note
Supply voltage	Vcc	4.5	5.0	5.5	V	
	Vss	0	0	0	V	
Input high voltage	V _{IH}	2.2	-	Vcc+0.3	V	
Input low voltage	VIL	-0.3	-	0.8	V	1
Ambient temperature range	Та	-40	-	+85	°C	

Note 1. -3.0V for pulse ≤ 30 ns (full width at half maximum)

DC Characteristics

Parameter	Symbol	Min.	Тур.	Max.	Unit		Test conditions	
Input leakage current		-	-	1	μΑ	Vin = Vss t	o Vcc	
Output leakage current	110	_	_	1	μА	CS# =V _{IH} or OE# =V _{IH} ,		
	110			'	μιν	VI/O =Vss t	to Vcc	
Average operating current	Icc ₁	_	25	35	mA		duty = 100%, $II/O = 0mA$,	
	1001		20	00	, \	CS# =V _{IL} , (Others = V _{IH} /V _{IL}	
						Cycle =1µs	s, duty =100%, II/O = 0mA,	
	Icc2	-	2	4	mA	CS# ≤ 0.2\	/,	
						V _{IH} ≥ Vcc-0	.2V, V _{IL} ≤ 0.2V	
Standby current	I _{SB}	_	_	3	mA	CS# =V _{IH} ,		
	128	_		3	ША	Others = Vss to Vcc		
Standby current			0.6*1	_	_	.05°0	Vin = Vss to Vcc,	
		-	0.6	2	μΑ	~+25°C	CS# ≥ Vcc-0.2V	
						. 4000		
		-	-	3	μΑ	~+40°C		
	I _{SB1}					7000		
		-	-	8	μΑ	~+70°C		
				40	_	.05%		
		-	-	10	μΑ	~+85°C		
Output high voltage	Vон	2.4	-	-	V	I _{OH} = -1mA		
	V _{OH2}	Vcc	_	_	V	Iон = -0.1m	nA	
	VOIIZ	- 0.5				1011 0.111	u ·	
Output low voltage	Vol	-	-	0.4	V	I _{OL} = 2mA		

Note 1. Typical parameter indicates the value for the center of distribution at 5.0V (Ta= 25°C), and not 100% tested.

Capacitance

 $(Vcc = 4.5V \sim 5.5V, f = 1MHz, Ta = -40 \sim +85^{\circ}C)$

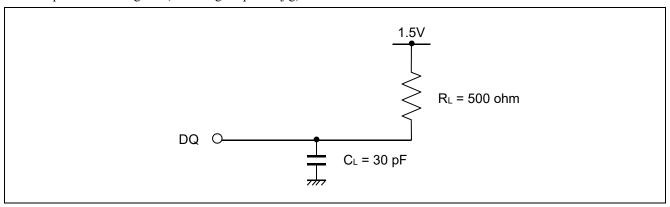
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions	Note
Input capacitance	C in	-	-	6	pF	Vin =0V	1
Input / output capacitance	C 1/0	-	-	8	pF	VI/O =0V	1

Note 1. This parameter is sampled and not 100% tested.

AC Characteristics

Test Conditions (Vcc = 4.5V ~ 5.5 V, Ta = $-40 \sim +85$ °C)

- Input pulse levels: VIL = 0.6V, VIH = 2.4V
- Input rise and fall time: 5ns
- Input and output timing reference level: 1.5V
- Output load: See figures (Including scope and jig)



Read Cycle

Parameter	Symbol	Min.	Max.	Unit	Note
Read cycle time	t _{RC}	55	-	ns	
Address access time	t _{AA}	-	55	ns	
Chip select access time	t _{ACS}	-	55	ns	
Output enable to output valid	toE	-	30	ns	
Output hold from address change	tон	10	-	ns	
Chip select to output in low-Z	tcLz	5	-	ns	2,3
Output enable to output in low-Z	tolz	5	-	ns	2,3
Chip deselect to output in high-Z	tcHZ	0	20	ns	1,2,3
Output disable to output in high-Z	tonz	0	20	ns	1,2,3

Write Cycle

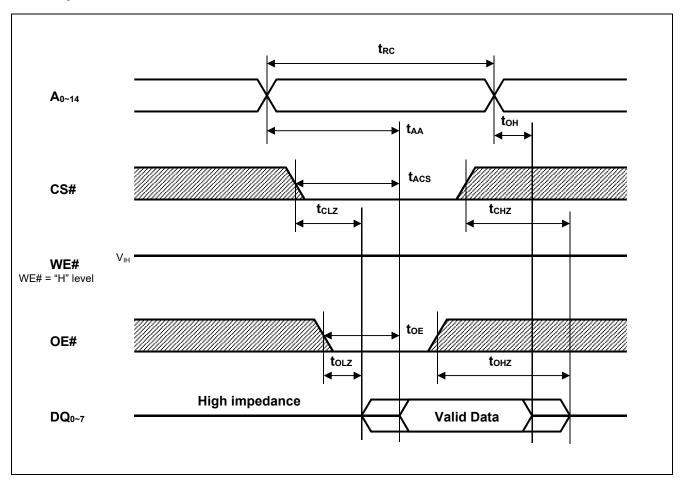
Parameter	Symbol	Min.	Max.	Unit	Note
Write cycle time	twc	55	-	ns	
Address valid to end of write	t _{AW}	50	-	ns	
Chip select to end of write	tcw	50	-	ns	5
Write pulse width	twp	40	-	ns	4
Address setup time	t _{AS}	0	-	ns	6
Write recovery time	twR	0	-	ns	7
Data to write time overlap	t _{DW}	25	-	ns	
Data hold from write time	t₀н	0	-	ns	
Output enable from end of write	tow	5	-	ns	2
Output disable to output in high-Z	tонz	0	20	ns	1,2
Write to output in high-Z	twnz	0	20	ns	1,2

Note

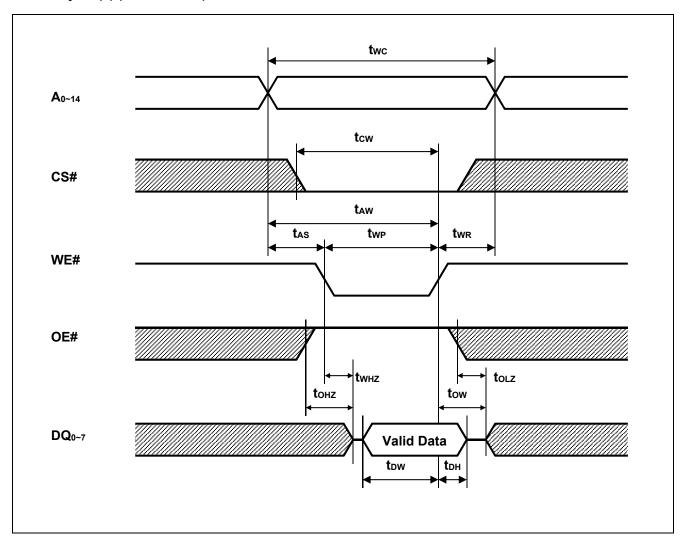
- 1. t_{CHZ} , t_{OHZ} and t_{WHZ} are defined as the time at which the outputs achieve the open circuit conditions and are not referred to output voltage levels.
- 2. This parameter is sampled and not 100% tested.
- 3. At any given temperature and voltage condition, t_{HZ} max is less than t_{LZ} min both for a given device and from device to device.
- 4. A write occurs during the overlap of a low CS#, a low WE#.
 - A write begins at the latest transition among CS# going low and WE# going low.
 - A write ends at the earliest transition among CS# going high and WE# going high.
 - t_{WP} is measured from the beginning of write to the end of write.
- 5. t_{CW} is measured from the later of CS# going low to end of write.
- 6. tas is measured the address valid to the beginning of write.
- 7. twR is measured from the earliest of CS# or WE# going high to the end of write cycle.
- 8. Don't apply inverted phase signal externally when DQ pin is output mode.

Timing Waveforms

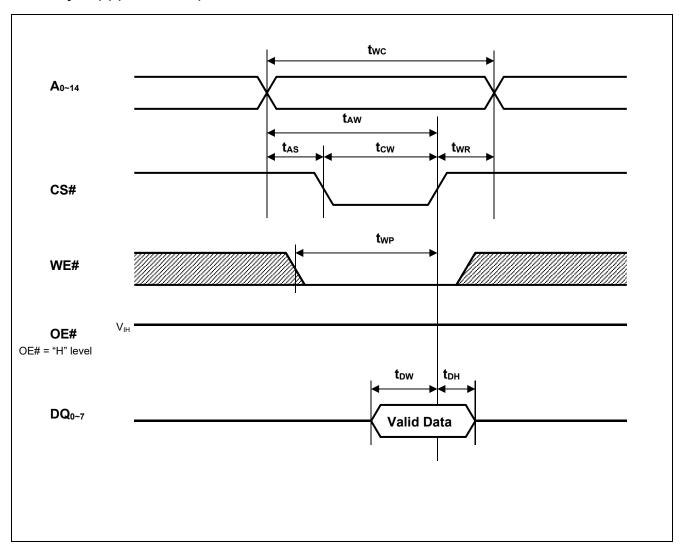
Read Cycle



Write Cycle (1) (WE# CLOCK)



Write Cycle (2) (CS# CLOCK)

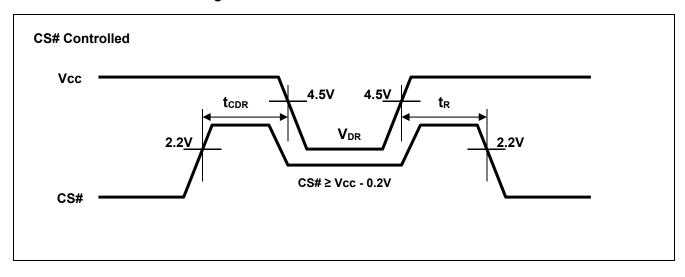


Low Vcc Data Retention Characteristics

Parameter	Symbol	Min.	Тур.	Max.	Unit		Test conditions*2
V _{CC} for data retention	V_{DR}	2.0	-	5.5	>	Vin ≥ 0V, CS# ≥ Vcc	c-0.2V
	Iccdr	-	0.6*1	2	μΑ	~+25°C	
5		-	1	3	μΑ	~+40°C	Vcc=3.0V, Vin ≥ 0V, CS# ≥ Vcc-0.2V
Data retention current		-	-	8	μΑ	~+70°C	C5# 2 VCC-0.2V
		-	-	10	μΑ	~+85°C	
Chip deselect time to data retention	t _{CDR}	0	-	-	ns	Soo roton	tion waveform
Operation recovery time	t _R	5	-	-	ms	See retention waveform.	

Note 1. Typical parameter indicates the value for the center of distribution at 3.0V (Ta= 25°C), and not 100% tested.

Low Vcc Data Retention Timing Waveforms



^{2.} CS# controls address buffer, WE# buffer, OE# buffer and Din buffer. If CS# controls data retention mode, Vin levels (address, WE#, OE#, DQ) can be in the high impedance state.

Revision History	R1LP5256E Series Data Sheet

		Description					
Rev.	Date	Page	Page Summary				
1.00	2017.1.27	-	First Edition issued				
2.00	2019.10.29	p.1	Revised orderable part name information.				

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